DGG OR DL PACKAGE (TOP VIEW)

10E

101 🛮 2

1Q2 🛚 3

GND 4

1Q3 🛮 5

104 6

V_{CC} <u>□</u> 7

1Q5 🛮 8

1Q6 49

1Q7 | 10 GND | 11

1Q8 🛮 12

1Q9 | 13 1Q10 | 14

2Q1 15

2Q2 L 16

2Q3 L 17

GND 1 18

2Q4 🛮 19

2Q5 L 20 2Q6 L 21

V_{CC} 4 22

2Q7 🛮 23

2Q8 **1** 24

GND 25

2Q9 [] 26

2Q10 **1**27

2OE 28

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56 🛭 1LE

55 1D1

54 🛭 1D2

53 🛮 GND

52 D 1D3

50 ∐ V_{CC}

49 🛮 1D5

48 1 1D6

47 🛮 1D7

46 GND

45 D 1D8

44 🛮 1D9

43 D10

42 2D1

41 D 2D2

40 L 2D3

39 | GND

38 🛮 2D4

37 D 2D5

35 D V_{CC}

34 🛮 2D7

33 D 2D8

32 D GND

31 2D9

30 D2D10

29 🛮 2LE

36 2D6

51 1D4

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Widebus™	Fan	nily	

- EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process
- Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

NOTE: For tape and reel order entry:

The DGGR package is abbreviated to GR.

description

This 20-bit bus-interface D-type latch is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74ALVCH162841 features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, unidirectional bus drivers, and working registers.

The SN74ALVCH162841 can be used as two 10-bit latches or one 20-bit latch. The 20 latches are transparent D-type latches. The device has

noninverting data (D) inputs and provides true data at its outputs. While the latch-enable (1LE or 2LE) input is high, the Q outputs of the corresponding 10-bit latch follow the D inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

A buffered output-enable $(1\overline{OE} \text{ or } 2\overline{OE})$ input can be used to place the outputs of the corresponding 10-bit latch in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly.

OE does not affect the internal operation of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The outputs, which are designed to sink up to 12 mA, include equivalent 26- Ω resistors to reduce overshoot and undershoot.



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TEXAS INSTRUMENTS

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description (continued)

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

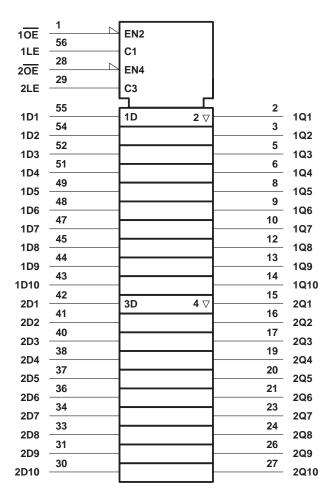
Active bus-hold circuitry is provided to hold unused or floating inputs at a valid logic level.

The SN74ALVCH162841 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each 10-bit latch)

	INPUTS	OUTPUT	
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	Χ	Q ₀
Н	X	Χ	Z

logic symbol†

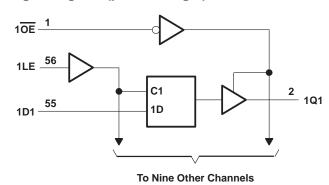


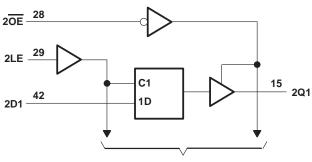
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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logic diagram (positive logic)





To Nine Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Input voltage range, V _I (see Note 1)	–0.5 V to 4.6 V
Output voltage range, V _O (see Notes 1 and 2)	–0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)	
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, I _O	±50 mA
Continuous current through each V _{CC} or GND	±100 mA
Package thermal impedance, θ_{JA} (see Note 3): DGG package	81°C/W
DL package	
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 4.6 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
Vcc	Supply voltage		1.65	3.6	V
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		
V_{IH}	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		
		V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}	
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	
VI	Input voltage		0	Vcc	V
۷o	Output voltage		0	VCC	V
		V _{CC} = 1.65 V		-2	
la	High-level output current	V _{CC} = 2.3 V		-6	A
ЮН		V _{CC} = 2.7 V		-8	mA
		V _{CC} = 3 V		-12	
		V _{CC} = 1.65 V		2	
1.	Low-level output current	V _{CC} = 2.3 V	6 8		mA
lOL		V _{CC} = 2.7 V			
		V _{CC} = 3 V		12	
Δt/Δν	Input transition rise or fall rate	-		10	ns/V
TA	Operating free-air temperature		-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDITIONS	vcc	MIN	TYP [†]	MAX	UNIT	
		$I_{OH} = -100 \mu\text{A}$	1.65 V to 3.6 V	V _{CC} -0.:	2			
		$I_{OH} = -2 \text{ mA}$	1.65 V	1.2				
VOH	$I_{OH} = -4 \text{ mA}$	2.3 V	1.9					
	I _{OH} = -6 mA	2.3 V	1.7			V		
		10H = -0 IIIA	3 V	2.4				
		$I_{OH} = -8 \text{ mA}$	2.7 V	2				
VOH VOL II		I _{OH} = -12 mA	3 V	2				
		I _{OL} = 100 μA	1.65 V to 3.6 V			0.2		
		I _{OL} = 2 mA	1.65 V			0.45		
		I _{OL} = 4 mA	2.3 V			0.4		
VOL		La. C mA	2.3 V			0.55	V	
		IOL = 6 mA	3 V			0.55		
		I _{OL} = 8 mA	2.7 V			0.6		
		I _{OL} = 12 mA	3 V			0.8		
Ιį		V _I = V _{CC} or GND	3.6 V			±5	μΑ	
		V _I = 0.58 V	1.65 V	25				
		V _I = 1.07 V	1.65 V	-25				
II(hold)		V _I = 0.7 V	2.3 V	45				
		V _I = 1.7 V	2.3 V	-45			μΑ	
		V _I = 0.8 V	3 V	75				
		V _I = 2 V	3 V	-75				
		$V_{I} = 0 \text{ to } 3.6 \text{ V}^{\ddagger}$	3.6 V			±500		
loz		$V_O = V_{CC}$ or GND	3.6 V			±10	μΑ	
Icc		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			40	μΑ	
ΔlCC		One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	3 V to 3.6 V			750	μΑ	
C.	Control inputs	Vi – Voe or CND	3.3 V		4.5			
Ci	Data inputs	V _I = V _{CC} or GND	3.3 V	6.5			pF	
Со	Outputs	$V_O = V_{CC}$ or GND	3.3 V		7		pF	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER		V _{CC} = 1.8 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
			MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _W	Pulse duration, LE high or low	§		3.3		3.3		3.3		ns
t _{su}	Setup time, data before LE↑	§		0.9		0.7		1.1		ns
th	Hold time, data after LE↑	§		1.2		1.5		1.1		ns

[§] This information was not available at the time of publication.



[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

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switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V	V _{CC} =	2.5 V 2 V	V _{CC} =	2.7 V	V _{CC} =	3.3 V 3 V	UNIT
	(INPOT) (OUTPO	(001F01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
^t pd	D	Q	†	1	5.3		5.2	1.2	4.3	ns
	LE		†	1	5.9		5.6	1	4.7	115
t _{en}	ŌĒ	Q	†	1	6.5		6.5	1	5.3	ns
^t dis	ŌĒ	Q	†	1.1	5.6		4.9	1.3	4.4	ns

[†] This information was not available at the time of publication.

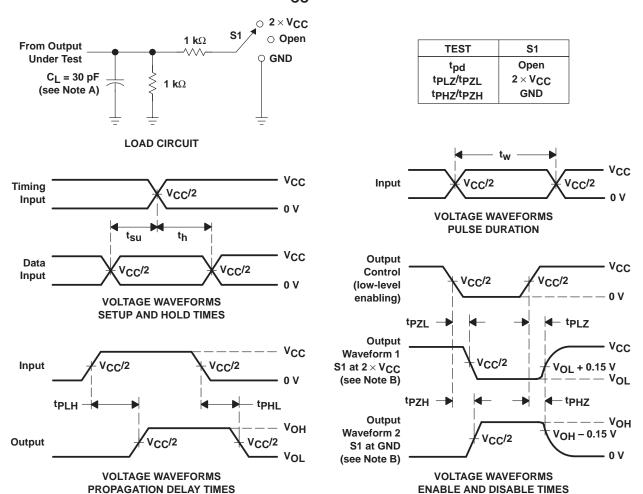
operating characteristics, T_A = 25°C

PARAMETER			TEST CO	MOITIONS	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT	
PARAMETER		TEST CONDITIONS		TYP	TYP	TYP	ONIT		
<u> </u>	Power dissipation capacitance	Outputs enabled	C 0	f = 10 MHz	†	24	27	pF	
Cpd		Outputs disabled	$C_L = 0$,	1 = 10 IVID2	†	2	2	þг	

[†] This information was not available at the time of publication.

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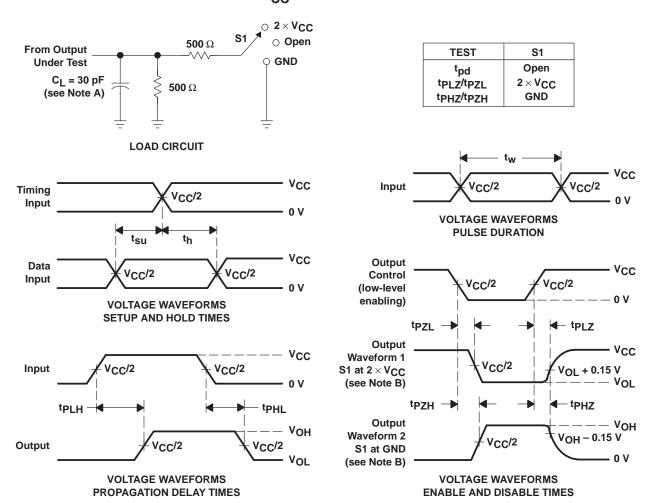
PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V}$



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.5 V \pm 0.2 V



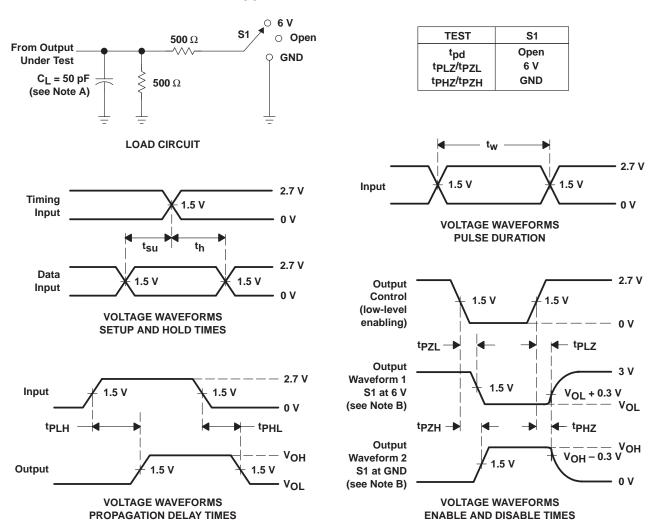
- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLZ and tpHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



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PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.7 V AND 3.3 V \pm 0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms

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